

CHIP TYPE TANTALUM SOLID ELECTROLYTIC CAPACITORS

Upgrade! MCM Series

- MCE Series
- Resin molded chip type
- ●Lead free type
- ●Extended capacitance range (1~2 rank) than MCS series
- ●Low profile, small-sized and large Capacitance



SPECIFICATIONS

●Smaller than MCS series

●Resin molded chip type

•Extended capacitance range

(1~2 rank) than MCS series

Items	Requirements								Test Conditions		
Category temperature range	-55 to +125	5°C(+85°C m									
Rated Voltage range	4 to 35Vdc										
Rated Capacitance range	1.0 to 330µ	F	f=120Hz, 20℃								
Rated Capacitance tolerance	±20%(M)										
Leakage current	I≦0.01CV (or 0.5(µA) W	Refer JIS C 5102. 7.7 .								
(L.C.)	I: Leakage	current (µA	After 5 minutes of applying rated voltage at 20℃								
Dissipation factor	Rated Volta	age (V)	1.0	1.5 to 10 15	to 68	100 to 330			Refer JIS C 5102. 7.9 .		
(tan∂)	D.F. (%) ma	ax.	f=120Hz, 20℃								
	D.F. (%) max. 4 (6) 6 (8) 8 10 (11) The following specifications shall be satisfied for P size.								(): Applies for R.V. 4Vdc and		
	Rated Capac	<u> </u>	4			16V			A to D size		
	D.F. (%) ma	. ,	10 8					1 11 2 2 2 2			
Characteristics	Temperatu		-55	+85		+1	25		Shall meet the table values.		
at high and	Cap. chang	` ,	≦±10			<u>≤</u> +	-		Refer JIS C 5102. 7.12 .		
Low temperature	Gapt on any	C=1.0µF	6(8)	4(6)		6(8			(): Applies for R.V. 4V _{dc} and		
-		C=1.5 to 10µF	8(10)	6(8)		8(1	,		A to D size		
	D.F. (%) max.	C=15 to 68µF	10	8		10			A to D size		
		C=100 to 330µF	12(13)	10(11)		12(
		0=100 to σσσμί	12(10)	` ′	5(πΔ)						
	Leakage curre	ent (µA) max.		Solution S(μA) Whichever is greater.		≦0.125CV or 6.25(µA) Whichever is greater.					
	The following	na specifica	tions shal				is greater.				
	Temperature (°C)		rations shall be satisfied for P size.		25]					
	Cap. change(%)		-55 +85 ≤±15 ≤±15		+125 ≤±20						
	Сар. спапо		12			1:					
	D.F. (%) max.	4V 6.3 to 16V	10	8	10						
		0.3 10 16 1	10	_	- (· · A)	10 050 / -					
	Leakage current (µA) max.			≦0.1CV or 5(μA) Whichever is greater.		≦0.25CV o Whichever	" /				
Damp heat,	Cap. chang	je	less than ± 10%						Refer JIS C 5102. 9.5.		
steady state	D.F.		Shall not exceed the value in Dissipation factor						40°C 90~95%RH 500hrs.		
	Leakage cu	ırrent (L.C.)	Shall not exceed the value in Leakage current				current				
	The following	ng specificat	ations shall be satisfied for P size.								
	Cap. change (%)		less than ±20%								
	D.F. (%) max.		4V : 15, 6.3 to 10V : 12								
	Leakage current (L.C.)		Shall not exceed the initial limit Leakage current				current				
Surge			4 to 6.3V Within ± 12%					(): Applies for P size	Refer JIS C 5102. 7.14 .		
_	Cap. change		10 to 16V Within ± 8% (Within ±12%)				2%)		85°C Surge voltage 1000cycles		
			20 to 35V Within ± 5% 1)						(30sec-on, 330sec-off).		
	D.F.		Shall not exceed 150% of the initial limit								
			Shall not exceed the initial limit Leakage current				current				
Rated ripple voltage	See Rated	ripple voltag	ge page, p	olease.							
Resistance to			4 to 10		8% (\	Vithin ±20	1%)	(): Applies for P size	Refer JIS C 5143 Appendix 1.		
soldering heat	Cap. change		16 to 35V Within ± 5% (Within ±10%)				%)		260℃ 5 sec.		
	D.F.		Shall not exceed the initial limit Dissipation factor			on factor					
	H	ırrent (L.C.)	Shall not exceed the initial limit Leakage current								
Endurance	Cap. change D.F. (%) max.		4 to 6.3V Within ± 12%						Refer JIS C 5102. 9.10 page.		
			10 to 35V Within ± 10%						85℃, Rated voltage, 1,000hrs.		
			4V : 15, 6.3 to 10V : 12						, ,		
	_ ` '		Shall not exceed the initial limit Leakage current				current				
	The following specifications shall be satisfied for P size.						ı				
	Cap. change		4V Within ± 20%								
			6.3 to 10V Within ± 12%								
	D.F. (%) max.		4V: 15, 6.3 to 16V: 12								
			Shall not exceed 125% of the initial limit				,				
Failure rate	1%/1000h							85°C, Rated voltage, 1Ω/V			
. andre rate	1,74,1000.						(power source impedance)				
Standard	JIS C 5143 characteristics LB							(power source impedance)			
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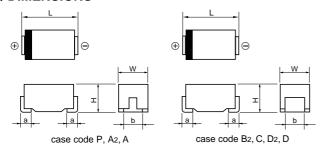
Note 1) Cap change of 25V-2.2 μ F(A size) and 25V-4.7 μ F (B2 size) is within \pm 10%.



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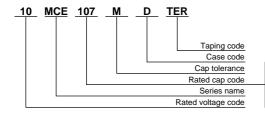


◆DIMENSIONS



					Unit : mm
Case code	L	W	Н	а	b
Р	2.0±0.2	1.25±0.2	1.2max.	0.5±0.5	0.9±0.2
A2	3.2±0.2	1.6 ±0.2	1.2max.	0.8±0.3	1.2±0.2
Α	3.2±0.2	1.6 ±0.2	1.6±0.2	0.8±0.3	1.2±0.2
B2	3.5±0.2	2.8 ±0.2	1.9±0.2	0.8±0.3	2.2±0.2
С	6.0±0.2	3.2 ±0.2	2.5±0.2	1.3±0.3	2.2±0.2
D2	5.8±0.2	4.6 ±0.2	3.2±0.2	1.3±0.3	2.4±0.2
D	7.3±0.2	4.3 ±0.2	2.8±0.2	1.3±0.3	2.4±0.2

◆PART NUMBERING SYSTEM



1,500,000

22,000,000

330,000,000

Capacitance (pF) Code

155

226

337

Rated voltage(Vdc)	2.5	4	6.3	10	16	20	25	35
code	2R5	4	6	10	16	20	25	35

STANDARD RATINGS

R.V(V _{dc}) (Code)	4	6.3	10	16	20	25	35
S.V.(Vdc)	(4)	(6)	(10)	(16)	(20)	(25)	(35)
μF (Code)	5	8	13	20	26	32	44
1.0 (105)		A2	A2	P, A2			Α
1.5 (155)		A2	A2	A2		Α	
2.2 (225)	A2	A2	P, A2	A2	Α	Α	B2
3.3 (335)	A2	A2	P, A2		Α		B2
4.7 (475)	A2	P, A2	P, A2	Α	Α	B2	
6.8 (685)	A2	P, A2	A2, A	Α	B2		С
10.0 (106)	P, A2	P, A2, A	A2, A	A, B2	B2	С	
15 .0 (156)	P, A2, A	A2, A	A, B2	B2	С	С	
22.0 (226)	A2, A	A, B2	B2	B2, C	С	D, D2	
33.0 (336)	A, B2	B2	B2	С	D, D2		
47.0 (476)	B2	B2	С	C, D, D2	D		
68.0 (686)	B2	С	C	D			
100.0 (107)	С	С	D, D2	D			
150.0 (157)	С	D, D2	D				
220.0 (227)	D, D2	D					
330.0 (337)	D						